

TL0374J

0.03 – 3.0 GHz GaAs Ultra Low Noise Amplifier

Application Note: TL0374J EVB C

Application Note
30 MHz~1000 MHz
3.3 V, 30 mA

Rev-2.3



List of Contents

1	General Description
2	TL0374J-EVB-C Board Details
3	TL0374J -EVB-C Bill of Material
4	TL0374J -EVB-C Biasing sequence
5	TL0374J -EVB-C Board Measurement Summary
6	TL0374J -EVB-C Board Measurement Results

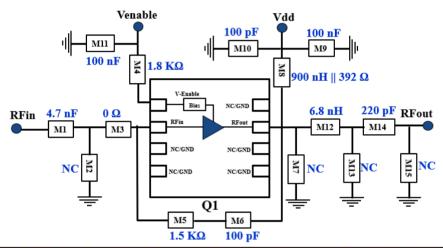


1. **General Description**

The TL0374J is a broadband, ultra-low Noise Amplifier (LNA) providing high gain and linearity. With a simple input and output match, this LNA can be tuned for different frequency bands targeting LTE (small cells and infrastructure) and any other applications requiring low noise, high gain, and linearity. For > 3 GHz frequency band, TL0375J can be considered. The TL0374J is packaged in a compact, low-cost Dual Flat No Lead (DFN) $2 \times 2 \times 0.75$ mm, 8 pin plastic package.

TL0374J-EVB-C is an evaluation board specially tuned for frequency range of 30 MHz~1000 MHz applications. Its high gain, low noise performance makes it suitable.

2. TL0374J-EVB-C Board Details



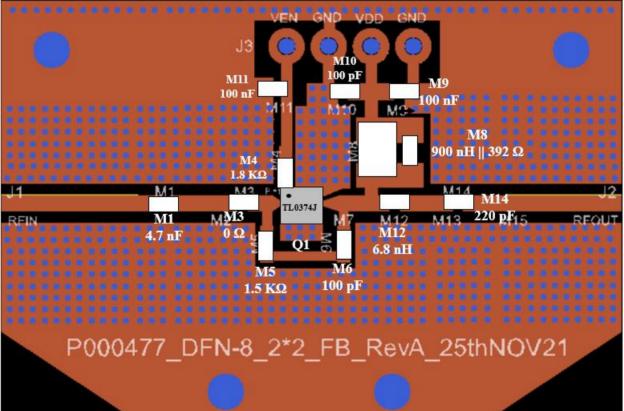


Figure 2.1 TL0374J-EVB-C 30 MHz ~ 1000 MHz Schematic and EVB Layout



3. TL0374J-EVB-C Bill of Material

Component ID	Value	Manufacturer Recommended Part Number		
M1	4.7 nF, 50 V	Murata	GRM1885C1H472JA01D	
M3	0 Ω	Panasonic ERJ-2GE0R00X		
M4	1.8 ΚΩ	Panasonic ERJ-2RKF1801X		
M5	1.5 ΚΩ	Panasonic	ERJ-2RKF1501X	
M6, M10	100 pF	AVX	04025A101JAT4A	
M8	900 nH	Coil craft	1008AF-901XJLC	
M8	392 Ω	Panasonic ERJ-UP3F3920V		
M9, M11	100 nF	TDK C1005X7R1H104K050BE		
M12	6.8 nH	Coil craft 0402HP-6N8XJRW		
M14	220 pF	Kemet	C0402C221K5GACAUTO	
Q1	GaAs LNA	Tagore Tech TL0374J		
PCB		Rogers RO4350B, 20 mils, 1 oz copper		

Table 3.1 TL0374J-EVB-C BOM

4. TL0374J-EVB-C Biasing Sequence

Turn ON Device	Turn OFF Device		
1. Set Venable to +3.3 V	1. Turn RF power off		
2. Set V _{DD} to +3.3 V	2. Turn off V _{DD}		
3. Device will draw required IDQ current	3. Turn off Venable		
4. Apply RF power			

Table 4.1 TL0374J-EVB-C Bias and Sequencing

5. TL0374J-EVB-C Board Measurement Summary

Frequency (MHz)	De-embedded Noise figure (dB)	Gain(dB)	OP1 (dBm)	OIP3(dBm) Fspacing:1 MHz 0 dBm Pout/tone	S11(dB)	S22(dB)	Mu1
30	1.1	25.6	14.4	28.4	-13.8	-22.7	1.1
100	0.7	25.7	14.3	27.5	-12.5	-23.8	1.2
250	0.6	25.2	14.6	28.1	-12.9	-17.2	1.3
500	0.6	23.9	14.7	28.7	-14.8	-14.6	1.5
750	0.5	22.6	15.2	29.1	-18.0	-18.4	1.7
1000	0.5	21.3	14.9	29.3	-26.3	-28.4	1.7

Table 5.1 TL0374J-EVB-C Electrical Characteristics Summary



6. TL0374J-EVB-C Test Results

All the tests are carried out at room temperature.

6.1. S parameters

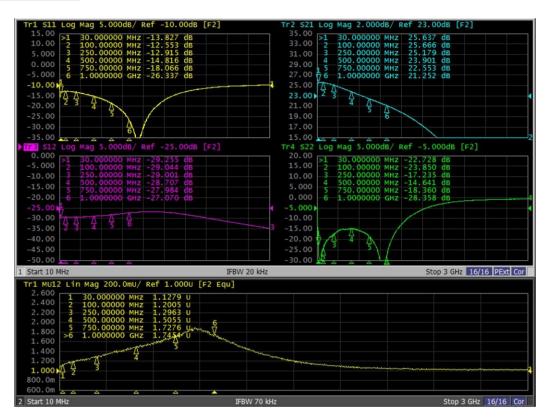
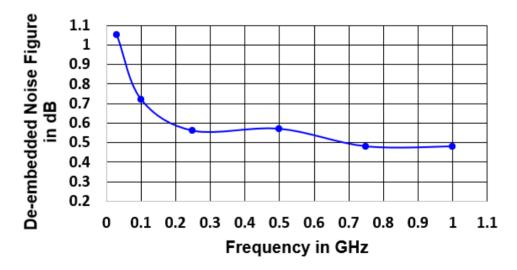


Figure 6.1.1. S parameters of TL0374J-EVB-C

6.2. <u>De-embedded Noise Figure</u>



^{**} **Note:** Trace loss is around 0.01-0.03 dB. So SMA to SMA NF will lie between 1.05 dB to 0.5 dB.

Figure 6.2.1. De-embedded Noise Figure mode of TL0374J-EVB-C



6.3. Large Signal Test Results

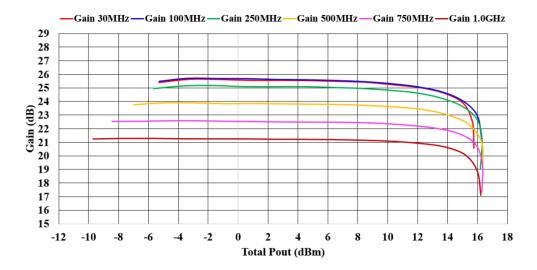


Figure 6.3.1. Gain Vs Pout of TL0374J-EVB-C

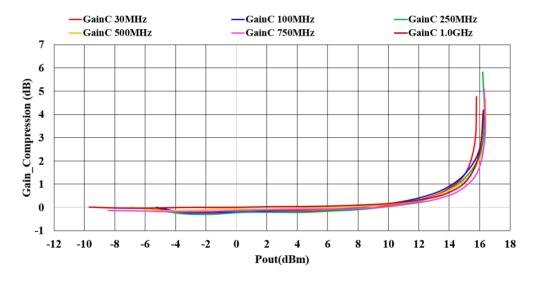


Figure 6.3.2. Gain compression Vs Pout of TL0374J-EVB-C

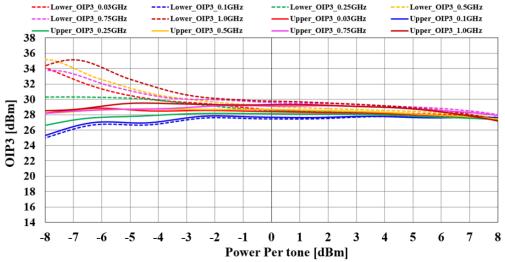


Figure 6.3.3. Output 3rd Order Intercept Point of TL0374J-EVB-C



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